

CMOS Digital Integrated Circuits Silicon Monolithic

TC7USB40MU

1. Functional Description

· Dual SPDT USB Switch

2. General

The TC7USB40MU is high-speed CMOS dual 1-2 multiplexer/demultiplexer. The low ON-resistance and the low capacitance of the switch allow connections to USB2.0 (480Mbps) application.

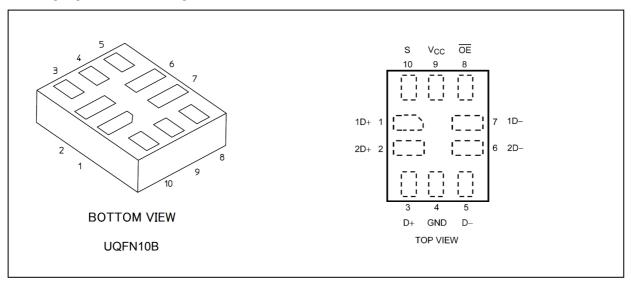
This device consists of dual individual two-inputs multiplexer/demultiplexer with common select input (S) and output enable (\overline{OE}) . The D+/D- inputs is connected to the 1D+/1D- or 2D+/2D- outputs determined by the combination both the select input (S) and output enable (\overline{OE}) . When the output enable (\overline{OE}) input is held high level, the switches are open with regardless the state of select inputs and a high-impedance state exists between the switches.

All inputs are equipped with protection circuits against static discharge.

3. Features

- (1) Supply voltage: $V_{CC} = 2.3 \text{ to } 4.3 \text{ V}$
- (2) Switch terminal ON-capacitance: $C_{\rm L/O}$ = 5 pF Switch ON (typ.) @ $V_{\rm CC}$ = 3.3 V
- (3) ON-resistance: $R_{ON} = 4.5 \Omega$ (typ.) @ $V_{CC} = 3 V$, $V_{IS} = 0 V$
- (4) R_{ON} flatness: $R_{ON(flat)} = 1.3 \Omega$ (typ.)@ $V_{CC} = 3 V$
- (5) Difference of ON-resistance between switches: $\Delta R_{ON} = 0.35 \Omega$ (typ.)@ $V_{CC} = 3 V$
- (6) Power-down protection provided on all inputs and outputs.
- (7) Ultra-small Package: UQFN10B
- (8) Application: USB2.0, I2C, I3C, UART

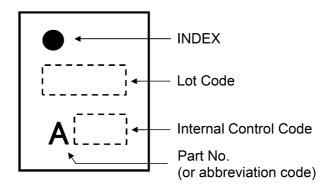
4. Packaging and Pin Assignment



Start of commercial production



5. Marking



6. Block Diagram

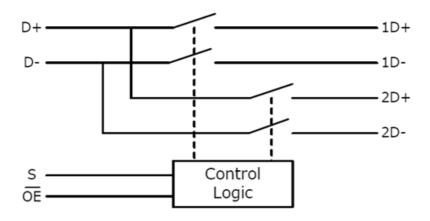


Fig. 6.1 Block Diagram

7. Principle of Operation

7.1. Truth Table

Input OE	Input S	Function
L	L	D+ port = 1D+ port, D- Port = 1D- Port
L	Н	D+ port = 2D+ port, D- Port = 2D- Port
Н	Х	Disconnect

X: Don't care



8. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	V _{CC}	_	-0.5 to 4.6	V
Input voltage (OE, S)	V _{IN}		-0.5 to 4.6	
Switch I/O voltage	Vs	V _{CC} = 0 V or Switch OFF	-0.5 to 4.6	
		Switch ON	-0.5 to V _{CC} +0.5	
Clamp diode current	I _{IK}	Control input	-50	mA
		Switch	±50	
Switch I/O current	I _S	_	50	
Power dissipation	P _D		200	mW
V _{CC} /ground current	I _{CC} /I _{GND}		±100	mA
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

9. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	V _{CC}			V
Input voltage (OE, S)	V _{IN}		0 to 4.3	
Switch I/O voltage	Vs	V _{CC} = 0 V or Switch OFF	0 to 4.3	
		Switch ON	0 to V _{CC}	
Operating temperature	T _{opr}	_	-40 to 85	°C
Input rise time	dt/dv		0 to 10	ns/V
Input fall time			0 to 10	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs and bus inputs must be tied to either V_{CC} or GND.



10. Electrical Characteristics

10.1. DC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 85°C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage (OE, S)	V _{IH}		_	2.3 to 3.0	0.50 × V _{CC}	-	_	V
				3.0 to 4.3	0.46 × V _{CC}	l		
Low-level input voltage (OE, S)	V _{IL}		_	2.3 to 4.3	ı	l	0.25 × V _{CC}	
Input leakage current (OE, S)	I _{IN}		V _{IN} = 0 to 4.3 V	2.3 to 4.3			±1	μА
Power-OFF leakage current	I _{OFF}		V _{IN} = V _{IS} = 0 to 4.3 V, See Fig. 11.10	0	ı	ı	±2	
Switch OFF-state leakage current	I _{SZ}		$V_{IS} = 0$ to V_{CC} , $\overline{OE} = V_{CC}$, See Fig. 11.11	2.3 to 4.3		l	±2	
ON-resistance	R _{ON}	(Note 1)	V _{IS} = 0 V, I _{IS} = 30 mA, See Fig. 11.9	3.0		4.5	6	Ω
			V_{IS} = 0.4 V, I_{IS} = 30 mA, See Fig. 11.9	3.0		4.8	6.7	
			V_{IS} = 3.0 V, I_{IS} = 30 mA, See Fig. 11.9	3.0		10	14	
Difference of ON-resistance between switches	ΔR _{ON}	(Note 1)	V _{IS} = 0.4 V, 1.0 V, I _{IS} = 30 mA	3.0		0.35		
ON-resistance flatness	R _{ON(flat)}	(Note 1)	V _{IS} = 0 V to 1.0 V, I _{IS} = 30 mA	3.0	- 1	1.3		
Quiescent supply current	I _{CC}		$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$ A	4.3	_	_	1	μА
	ΔI_{CC}		V _{IN} = 2.6 V (one input)	4.3	_	_	40	

Note: All typical values are at $T_a = 25$ °C.

Note 1: Measured by the voltage drop between D+/D- and 1D+/1D-,2D+/2D- pins at the indicated current through the switch. On-resistance is determined by the lower of the voltages on the two pins.

10.2. AC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 85°C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Тур.	Max	Unit
Propagation delay time	t _{PLH} /t _{PHL}	(Note 1)	C _L = 5 pF, See Fig. 11.1	3.3 ± 0.3	_	0.25		ns
Turn-ON time (S, OE to output)	t _{on}		R_L = 50 Ω , C_L = 5 pF, See Fig. 11.2		_	10	20	
Turn-OFF time (S, OE to output)	t _{off}				_	14	24	
Break before make	TBBM		R_L = 50 Ω , C_L = 5 pF, See Fig. 11.3		2		7	
Skew of opposite transitions of the same output (t _{PHL} - t _{PLH})	t _{SK(P)}	(Note 1)	C _L = 5 pF, See Fig. 11.4		ı	0.1		
Output skew (center port to any other port)	t _{SK(O)}	(Note 1)	C _L = 5 pF, See Fig. 11.5		_	0.1	_	

Note: All typical values are at Ta = 25°C. Note 1: Parameter guaranteed by design.



10.3. Analog Switch (Note) (Unless otherwise specified, T_a = -40 to 85°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Тур.	Max	Unit
OFF isolation (non-adjacent)	OIRR	R_T = 50 Ω , f = 240 MHz, See Fig. 11.6	3.3 ± 0.3	-	-24		dB
Crosstalk (non-adjacent)	Xtalk	R_T = 50 Ω , f = 240 MHz, See Fig. 11.7		_	-30	-	
-3dB Bandwidth	BW	R_L = 50 Ω , C_L = 0 pF, See Fig. 11.8		_	1500		MHz

Note: All typical values are at Ta = 25°C. Parameter guaranteed by design.

10.4. Capacitive Characteristics (Note) (Unless otherwise specified, Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance (OE, S)	C _{IN}	V _{IN} = 0 V	3.3	3	pF
Switch terminal OFF-capacitance (D+, D-)	C _{I/O}	$\overline{OE} = V_{CC}, V_{IS} = 0 V$		3	
Switch terminal OFF-capacitance (1D+, 1D-, 2D+, 2D-)]			2	
Switch terminal ON-capacitance	1	\overline{OE} = GND, V _{IS} = 0 V		5	

Note: Parameter guaranteed by design.



11. AC Test Circuits and Waveforms

(1D+, 1D-, 2D+, 2D-)

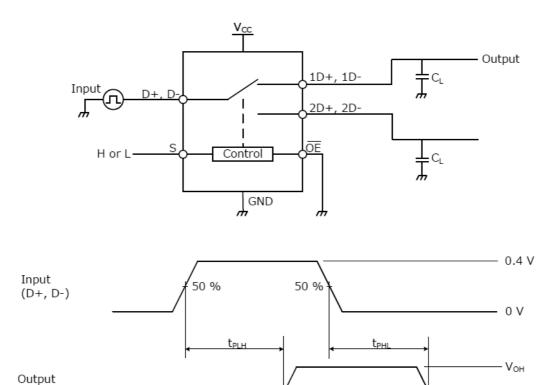


Fig. 11.1 Propagation Delay Time (t_{PLH}, t_{PHL})

50 %

50 %

 V_{OL}

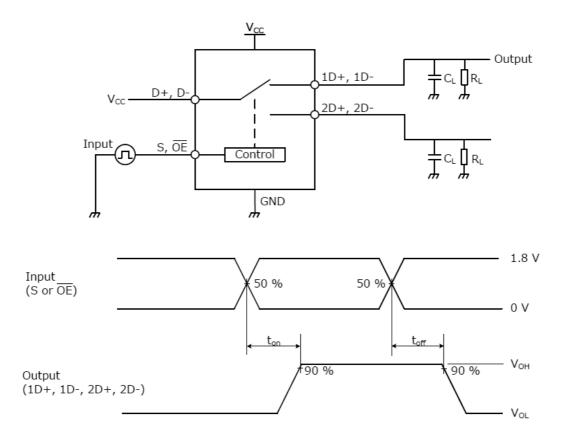


Fig. 11.2 Turn-ON and Turn-OFF Times (ton, toff)

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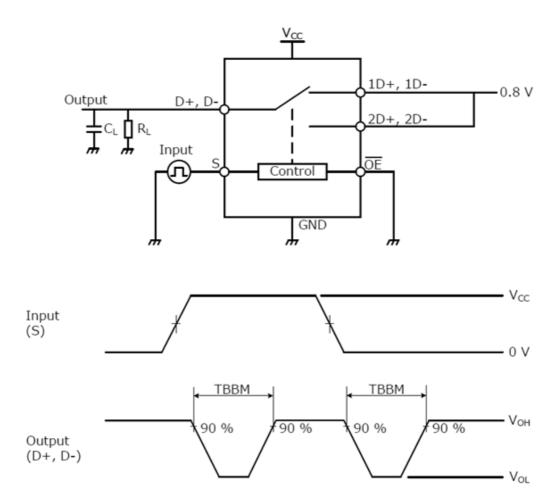


Fig. 11.3 Break Before Make (TBBM)



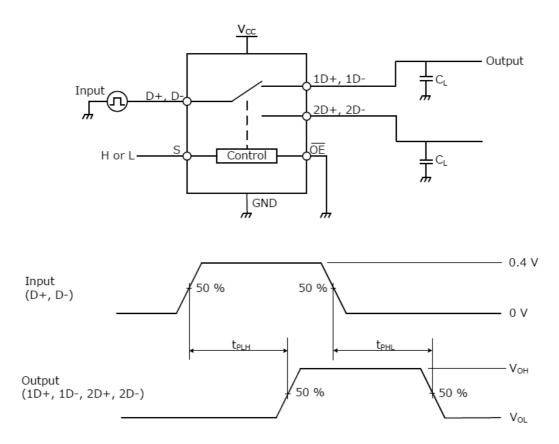


Fig. 11.4 Skew of opposite transitions of the same output $(t_{SK(P)} = |t_{PHL} - t_{PLH}|)$

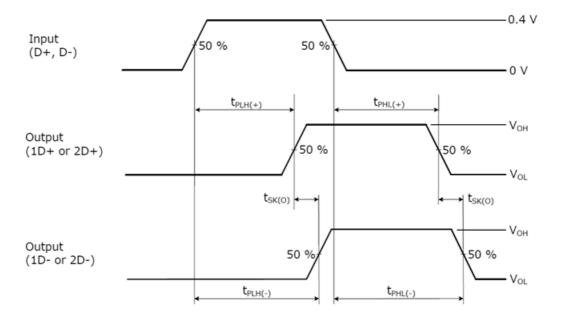


Fig. 11.5 Output Skew (center port to any other port)

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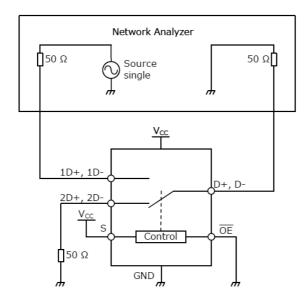


Fig. 11.6 OFF Isolation

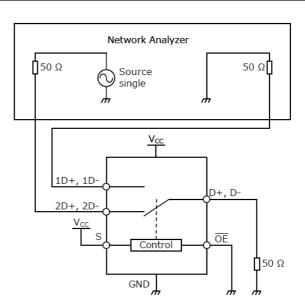


Fig. 11.7 Crosstalk

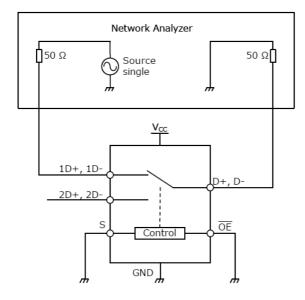


Fig. 11.8 -3dB Bandwidth



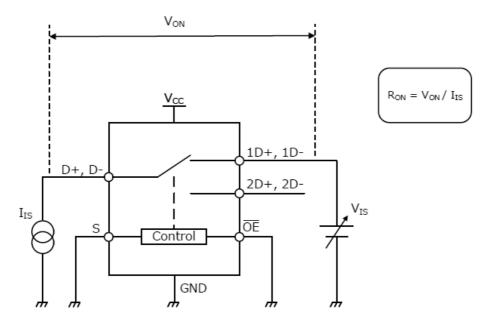


Fig. 11.9 ON-Resistance

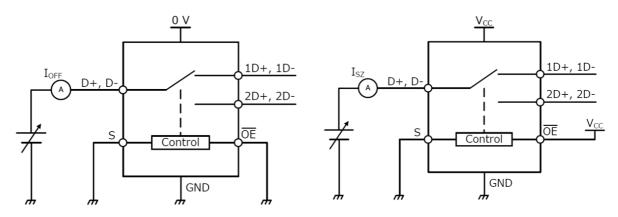


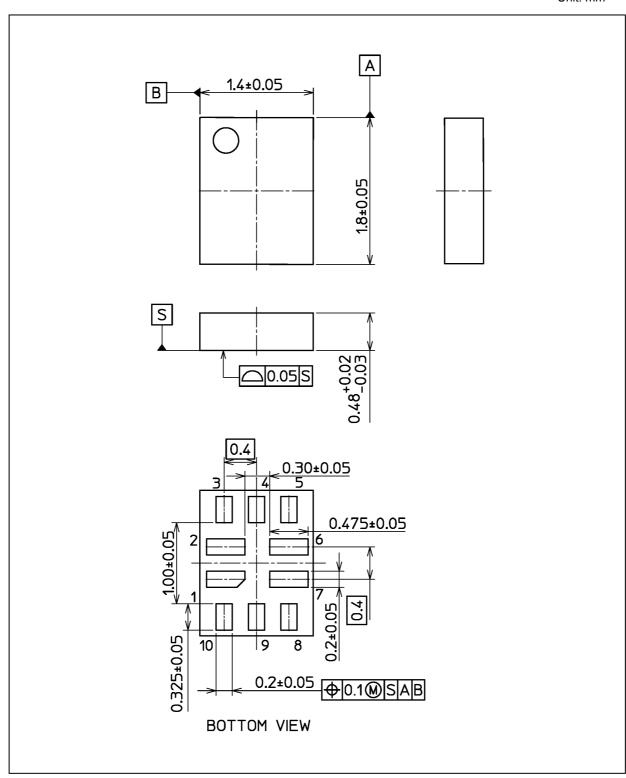
Fig. 11.10 Power-OFF Leakage Current

Fig. 11.11 Switch OFF-state leakage current



Package Dimensions

Unit: mm



This resins used in this product include no flame retardants.

Weight: 4.0 mg (typ.)

Package Na	nme(s)
Nickname: UQFN10B	

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